





MSP16065G1 650V Silicon Carbide Diode

Features

- -650-Volt Schottky Rectifier
- -Shorter recovery time
- -High-speed switching possible
- -High-Frequency Operation
- -Temperature-Independent Switching Behavior
- -Extremely Fast Switching
- -Positive Temperature Coefficient on VF

Benefits

- -Higher safety margin against overvoltage
- -Improved efficiency all load conditions
- -Increased efficiency compared to Silicon Diode alternatives
- -Reduction of Heat Sink Requirements
- -Parallel Devices Without Thermal Runaway
- -Essentialy No Switching Losses

Applications

- -Switch Mode Power Supplies
- -Power Factor Correction
- -Motor Drives
- -HID Lighting

Package



Type: TO-220 -2lead

1, Cathode 2, Anode



Absolute Maximum Ratings T_C = 25° C unless otherwise noted

Symbol	Parameter	MSP16065G1	Units
VRRM	Repetitive Peak Reverse Voltage	650	V
VRSM	Surge Peak Reverse Voltage	650	V
VDC	DC Blocking Voltage	650	V
IF	Continuous Forward Current @Tc=150°C	16	Α
IFRM	Repetitive Peak Forward Surge Current @TC=25°C tp = 10 ms, Half Sine Wave	105	А
IFSM	Non-Repetitive Peak Forward Surge Current @TC=25 ℃ tp= 10 ms, Half Sine Wave	135	Α
IF,Max	Non-Repetitive Peak Forward Surge Current @TC=25 ℃, tp = 10 us	1200	Α
Ptot	Power Dissipation @Tc=25°C @Tc=110°C	205 89	W
TJ , Tstg	Operating Junction and Storage Temperature	-55 to +175	°C

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Package Marking

Part Number		Top Marking	Package	Packing Method	MOQ	QTY
	MSP16065G1	MSP16065G1	T0-220C-2L	Tube	1000	5000

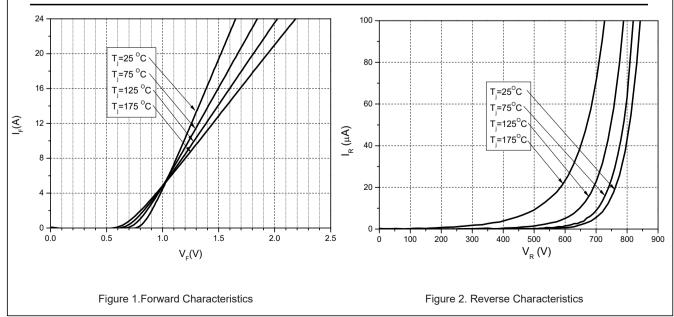
Electrical Characteristics T_c = 25° C unless otherwise noted

Symbol	Test Conditions	Test Conditions	Min	Тур	Max	Unit
VF	Forward Voltage	IF=16A, TC=25° C IF=16A, TC=175° C	-	1.45 1.75	1.8 3.0	٧
IR	Reverse Current	VR=650V, TC=25° C VR=650V, TC=175° C	-	4 40	20 200	μΑ
QC	Total Capacitive Charge	VR =400V, IF =16A TJ = 25° C Qc= $\int_{0}^{\nu_{r}} C (V) dv$	-	41	1	nC
С	Total Capacitance	VR =0V, TJ = 25° C, f=1MHz VR =200V, TJ = 25° C, f=1MHz VR =400V, TJ = 25° C, f=1MHz	-	860 85 60	,	pF
EC	Capacitance Stored Energy	VR=400V	-	8.2	-	μJ

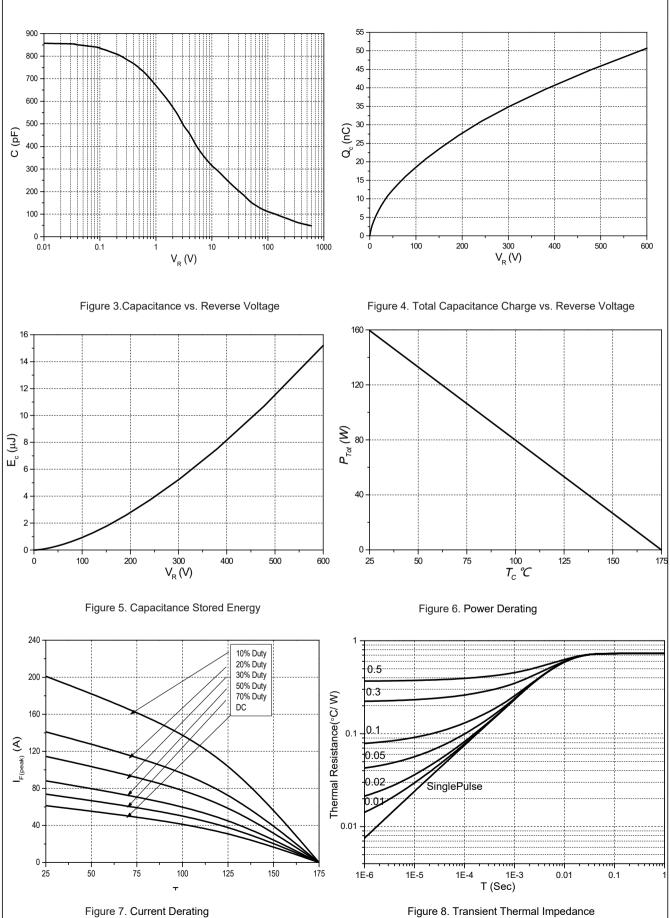
Thermal Characteristics

Symbol	Parameter	Тур	Unit
RθJC	Thermal Resistance from Junction to Case	0.73	°C/W

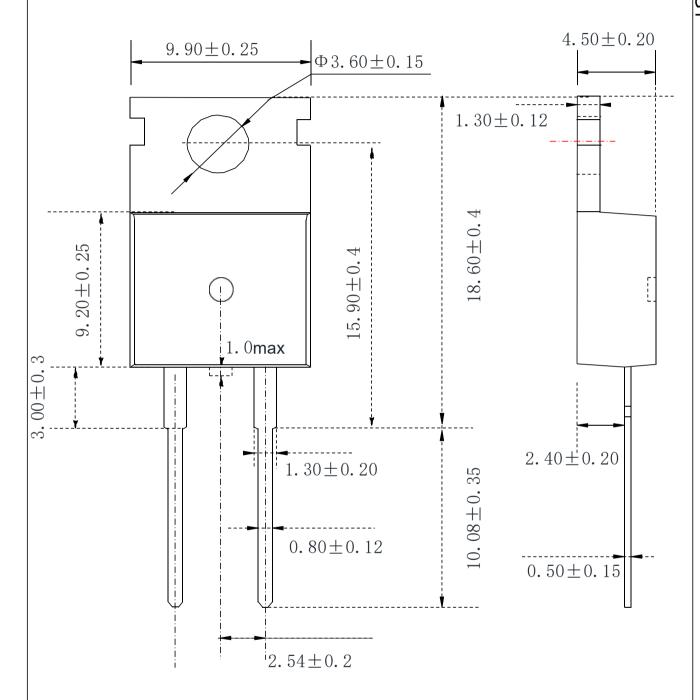
Typical Characteristics



Typical Characteristics



TO-220C-2L OUTLINE



NOTE:

1The plastic package is not marked as smooth surfaceRa=0.1;Subglossy surfaceRa=0.8 2.Undeclared tolerance ± 0.15 ,Unmarked filletRmax=0.25

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